

# **Enpirion® Power Datasheet**

EN5364QI 6A PowerSoC Voltage Mode Synchronous Buck PWM DC-DC Converter With Integrated Inductor

### **Description**

The EN5364QI is a Power Supply on a Chip (PwrSoC) DC to DC converter with integrated inductor, PWM controller, MOSFETS, and compensation providing the smallest possible solution size in a 68 pin QFN module. The switching frequency can be synchronized to an external clock or other EN5364QIs with the added capability of phasing multiple EN5364QIs as desired. Other features include precision ENABLE threshold, pre-bias monotonic start-up, margining, and parallel operation.

EN5364QI is specifically designed to meet the precise voltage and fast transient requirements high-performance of present and future applications such as set-top boxes/HD DVRs, LAN/SAN adapter cards, audio/video equipment, optical networking, multi-function printers, test measurement. embedded computing. and Advanced storage, and servers. circuit techniques, ultra high switching frequency, and very advanced, high-density, integrated circuit and proprietary inductor technology deliver highultra compact, non-isolated DC-DC conversion. Operating this converter requires very few external components.

The Altera Enpirion integrated inductor solution significantly helps to reduce noise. The complete power converter solution enhances productivity by offering greatly simplified board design, layout and manufacturing requirements.

All Altera Enpirion products are RoHS compliant and lead-free manufacturing environment compatible.

## Typical Application Circuit

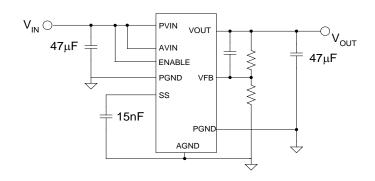


Figure 1: Typical Application Schematic

#### **Features**

- Integrated Inductor, MOSFETS, Controller in a 8 x 11 x 1.85mm package
- Wide input voltage range of 2.375V to 6.6V.
- > 20W continuous output power.
- High efficiency, up to 93%.
- Output voltage margining
- Monotonic output voltage ramp during startup with pre-biased loads.
- Precision Enable pin for accurate sequencing of power converters and Power OK signal.
- Programmable soft-start time.
- Soft Shutdown.
- 4 MHz operating frequency with ability to synchronize to an external system clock or other EN5364's.
- Programmable phase delays between synchronized units to allow reduction of input ripple.
- Master/slave configuration for paralleling multiple EN5364's for greater power output.
- Under Voltage Lockout, Over-current, Short Circuit, and Thermal Protection
- RoHS compliant, MSL level 3, 260C reflow.

# **Applications**

- Point of load regulation for low-power processors, network processors, DSPs, FPGAs, and ASICs
- Low voltage, distributed power architectures with 2.5V, 3.3V or 5V, 6V rails
- Computing, broadband, networking, LAN/WAN, optical, test & measurement
- AVV, high density cards, storage, DSL, STB, DVR, DTV, Industrial PC
- Beat frequency sensitive applications

- Applications requiring monotonic start-up with pre-bias
- Ripple voltage sensitive applications
- Noise sensitive applications
- Pin compatible with EN5394QI (9A)

## **Ordering Information**

Temp Rating				
Part Number	(°C)	<b>Package</b>		
EN5364QI	-40 to +85	68-pin QFN T&R		
EVB-EN5364QI	QFN Evaluation Board			

# **Pin Configuration**

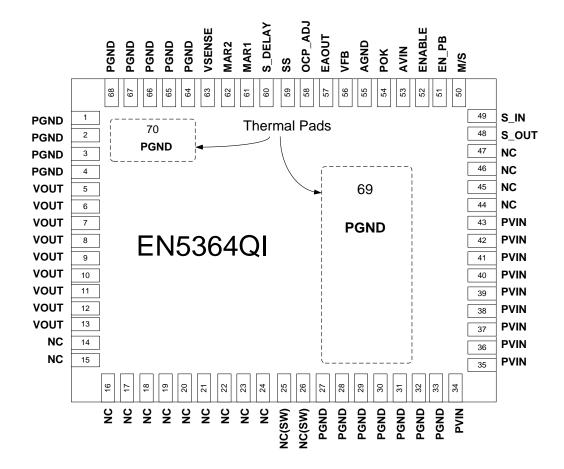


Figure 2: Pinout Diagram (Top View). All perimeter pins must be soldered to PCB.

2

# Pin Descriptions

PIN	NAME	FUNCTION
	NAME	FUNCTION
1-4,	DOND	Input/Output power ground. Connect these pins to the ground electrode of the input
27-33,	PGND	and output filter capacitors. See VOUT and PVIN descriptions for more details.
64-68		
5-13	VOUT	Regulated converter output. Connect to the load, and place output filter capacitor(s) between these pins and PGND pins 1-4 and 64-68.
		NO CONNECT: These pins must be soldered to PCB but not be electrically connected
14-24,	NC	to each other or to any external signal, voltage, or ground. These pins may be
44-47	110	connected internally. Failure to follow this guideline may result in device damage.
		NO CONNECT: These pins are internally connected to the common switching node of
	110 (0) 10	the internal MOSFETs. They must be soldered to PCB but not be electrically
25-26	NC(SW)	connected to any external signal, ground, or voltage. Failure to follow this guideline
		may result in device damage.
		Input power supply. Connect to input power supply, place input filter capacitor(s)
34-43	PVIN	between these pins and PGND pins 27-33.
		Clock Output. Depending on the mode, either a clock signal or the PWM signal is
48	S OUT	output on this pin. These signals are delayed by a time that is related to the resistor
	0_00.	connected between S_DELAY and AGND. Leave this pin floating if not needed.
		Clock Input. Depending on the mode, this pin accepts either an input clock to
49	S_IN	synchronize the internal switching frequency or the S_OUT signal from another
		EN5364QI. Leave this pin floating if it is not used.
		This is a Ternary Input. Floating the pin disables parallel operation. A low level
50	M/S	configures the device as Master and a High level configures the device as a slave.
		This is the Enable Pre-Bias Input. When this pin is pulled high, the Device will support
51	EN_PB	monotonic start-up under a pre-biased load. There is a 150k $\Omega$ pull-down on this pin.
		This is the Device Enable pin. A high level enables the device while a low level
52	ENABLE	disables the device.
53	AVIN	Input power supply for the controller. Needs to be connected to $V_{IN}$ at a quiet point.
	7.0	Power OK is an open drain transistor for power system state indication. POK is a
		logic high when VOUT is with -10% to +20% of VOUT nominal. Being an open drain
54	POK	output allows several devices to be wired to logically AND the function. Size pull-up
		resistor to limit current to 4mA when POK is low.
55	AGND	Ground return for the controller. Needs to be connected to a quiet ground.
	7 10 1 12	External Feedback input. The feedback loop is closed through this pin. A voltage
56	VFB	divider at V <sub>OUT</sub> is used to set the output voltage. The mid-point of the divider is
		connected to VFB. The control loop regulates to make the VFB node voltage 0.6V.
57	EAOUT	Optional Error Amplifier output. Allows for customization of the control loop.
		When this pin is pulled to AGND, the overcurrent protection trip point is increased by
58	OCP_ADJ	approximately 30%. Leave floating for default OCP threshold (see Electrical
	001_110	Characteristics table). Tie this pin to AGND for pin compatibility with the EN5394.
		A soft-start capacitor is connected between this pin to AGND. The value of the
59	SS	capacitor controls the soft-start interval and startup time.
	0.051.41/	A resistor is connected between this pin and AGND. The value of the resistor controls
60 S_DELAY	the delay in S_OUT. This pin can be left floating if the S_OUT function is not used.	
		These are 2 ternary input pins. Each pin can be a logical Lo, Logical Hi or Float
04.55	MAR1,	condition. 7 of the 9 states are used to modulate the output voltage by 0%, ±2.5%,
61-62	MAR2	±5% or ±10%. The 8th state is used to by-pass the delay in S_OUT. See Functional
		Description section.
63	VSENSE	This pin senses VOUT when the device is placed in the Back-feed (or Pre-bias) mode.
		Device thermal pads to be connected to the system gnd plane. See Layout
69, 70	PGND	Recommendations section.
	1	

## **Absolute Maximum Ratings**

CAUTION: Absolute Maximum ratings are stress ratings only. Functional operation beyond recommended operating conditions is not implied. Stress beyond absolute maximum ratings may cause permanent damage to the device. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

PARAMETER	SYMBOL	MIN	MAX	UNITS
Voltages on PVIN, AVIN, VOUT	$V_{IN}$	-0.5	7.0	V
Voltages on VSENSE, ENABLE, EN_PB, POK,		-0.5	$V_{IN} + 0.3$	V
Voltages on VFB, EAOUT, SS, S_IN, S_OUT, OCP_ADJ		-0.5	2.7	V
Voltages on MAR1, MAR2, M/S		-0.5	3.6	V
Storage Temperature Range	$T_{STG}$	-65	150	°C
Maximum Operating Junction Temperature	T <sub>J-ABS MAX</sub>		150	°C
Reflow Temp, 10 Sec, MSL3 JEDEC J-STD-020A			260	°C
ESD Rating (based on Human Body Model)			2000	V

# **Recommended Operating Conditions**

PARAMETER	SYMBOL	MIN	MAX	UNITS
Input Voltage Range	$V_{IN}$	2.375	6.6	V
Output Voltage Range	$V_{OUT}$	0.60	$V_{IN} - V_{DO}^{\dagger}$	V
Output Current	I <sub>LOAD</sub>	0	6	Α
Operating Ambient Temperature	T <sub>A</sub>	-40	+85	°C
Operating Junction Temperature	T <sub>J</sub>	-40	+125	°C

<sup>&</sup>lt;sup>†</sup>V<sub>DO (</sub>drop-out voltage) is defined as (I<sub>LOAD</sub> x Dropout Resistance). Please see Electrical Characteristics table.

# Thermal Characteristics

PARAMETER	SYMBOL	TYP	UNITS
Thermal Resistance: Junction to Ambient (0 LFM) <sup>††</sup>	$\theta_{JA}$	16	°C/W
Thermal Resistance: Junction to Case	$\theta_{ m JC}$	1	°C/W
Thermal Shutdown Trip Point	T <sub>SD</sub>	+150	°C
Thermal Shutdown Trip Point Hysteresis	T <sub>SDH</sub>	20	°C

<sup>††</sup> Based on a four-layer board and proper thermal design in line with JEDEC EIJ/JESD 51 Standards.

# **Electrical Characteristics**

NOTE:  $V_{\text{IN}}$ =5.5V over operating temperature range unless otherwise noted.

Typical values are at  $T_A = 25$ °C.

PARAMETER	SYMBOL	COMMENTS	MIN	TYP	MAX	UNITS
Input Voltage	$V_{IN}$		2.375		6.6	V
Under Voltage Lock out threshold	V <sub>UVLOR</sub> V <sub>UVLOF</sub>	V <sub>IN</sub> Increasing V <sub>IN</sub> Decreasing		2.2 2.1		V
Shut-Down Supply Current	Is	ENABLE=0V		250		μΑ
Feedback Pin Voltage	$V_{FB}$	$2.375V \le VIN \le 6.6V$ , $I_{LOAD} = 1A$ ; $T_A = 25$ °C	0.588	0.600	0.612	V
Feedback Pin Input Leakage Current <sup>1</sup>	I <sub>FB</sub>		-5		5	nA
Line Regulation	$\Delta V_{OUT\_LINE}$	$2.375V \le V_{IN} \le 6.6V$		0.035		%/V
Load Regulation	$\Delta V_{OUT\_LOAD}$	0A ≤ ILOAD ≤ 6A		-0.04		%/A
Temperature Regulation	$\Delta V_{ ext{OUT\_TEMP}}$	-40°C ≤ TEMP ≤ 85°C		0.001		%/°C
V <sub>OUT</sub> Rise Time	$T_{RISE}$	Measured from when $V_{IN} \ge V_{UVLOR}$ & ENABLE pin crosses logic high threshold. (4.7nF $\le C_{SS} \le 100$ nF)		$C_{SS}x$ 65k $\Omega$		
Rise Time Accuracy <sup>1</sup>	$\DeltaT_{RISE}$	4.7nF ≤ C <sub>SS</sub> ≤ 100nF	-25		+25	%
Output Dropout Voltage <sup>1</sup> Resistance <sup>1</sup>	$V_{DO} \ R_{DO}$	V <sub>INMIN</sub> – V <sub>OUT</sub> at Full Load Input to Output Resistance		240 40	480 80	mV mΩ
Maximum Continuous Output Current <sup>2</sup>	I <sub>OUT_MAX_CONT</sub>		6			Α
Current Limit Threshold	$I_{OCP}$	OCP_ADJ floating		10.5		Α
ENABLE pin: Disable Threshold Enable Threshold	V <sub>disable</sub> V <sub>enable</sub>	2.375V ≤ V <sub>IN</sub> ≤ 6.6V ENABLE pin logic low ENABLE pin logic high	1.00		1.0 1.30	V
ENABLE Lock-out time	t <sub>ENLO</sub>	Time for device to re-enable after a falling edge on ENABLE pin		2		ms
ENABLE Pin Input Current	I <sub>ENABLE</sub>	V <sub>IN</sub> = 5.5V		50		μА
Switching Frequency	F <sub>SWITCH</sub>	Free Running frequency		4		MHz
External S_IN Clock Frequency Lock Range	F <sub>PLL_LOCK</sub>	Frequency Range of S_IN Input Clock	3.6		4.4	MHz
S_IN Threshold – Low	$V_{S\_IN\_LO}$	S_IN Clock low level			0.8	V
S_IN Threshold – High	$V_{S\_IN\_HI}$	S_IN Clock high level	1.8		2.5	V
S_OUT Threshold - Low	$V_{S\_OUT\_LO}$	S_OUT Clock low level			0.5	V
S_OUT Threshold – High	$V_{s\_out\_HI}$	S_OUT Clock high level	1.8			V
S_IN Duty Cycle for External Synchronization <sup>1</sup>	SY <sub>DC_SYNC</sub>	M/S Pin Float or Low	20		80	%
S_IN Duty Cycle for Parallel Operation <sup>1</sup>	SY <sub>DC_PWM</sub>	M/S Pin High	10		90	%
Phase Delay vs. S_Delay Resistor value	$\Phi_{DEL}$	Delay in ns / $k\Omega$ Delay in phase angle / $k\Omega$ - @ 4MHz switching frequency		2 3		ns °

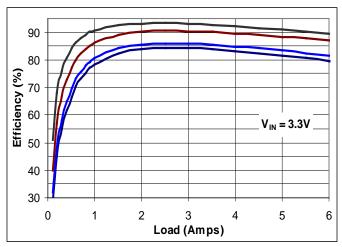
Phase Delay between S_IN and S_OUT <sup>1</sup>	$\Phi_{DEL}$	Phase delay programmable via resistor connected from S_Delay to AGND.	20		150	ns
Phase Delay between S_IN and S_OUT1	$\Phi_{DEL}$	Delay By-Pass Mode (MAR1 floating, MAR2 high)			10	ns
Phase Delay Accuracy <sup>1</sup>			-20		20	%
Pre-Bias Level	$V_{PB}$	Allowable Pre-Bias as a fraction of programmed output voltage (subject to a minimum of 300mV)	20		85	%
Non-Monotonicity	$V_{PB\_NM}$	Allowable non monotonicity		50		mV
POK Lower Threshold as a percent of V <sub>OUT</sub> <sup>3</sup>	POK <sub>LT</sub>	V <sub>OUT</sub> rising V <sub>OUT</sub> falling		92 90		%
POK Upper Threshold as a percent of V <sub>OUT</sub> <sup>3</sup>	POK <sub>UT</sub>	V <sub>OUT</sub> rising V <sub>OUT</sub> falling		120 115		%
POK Falling Edge Deglitch Delay <sup>4</sup>				60		μs
POK Output Low Voltage	$V_{POKL}$	With 4mA current sink into POK			0.4	V
POK Output High Voltage	$V_{POKH}$	$2.375V \le V_{IN} \le 6.6V$			$V_{IN}$	V
Ternary Pin Logic Low <sup>5</sup>	$V_{T-Low}$	Tie pin to GND		0		V
Ternary Pin Logic High⁵	$V_{\text{T-High}}$	Pull up to $V_{IN}$ through an external resistor $R_{EXT}$ – see Figure 5.		see Input Current below		
Ternary Pin Input Current (see Figure 5) <sup>5</sup>	I <sub>TERN</sub>	$\begin{aligned} &V_{\text{IN}} = 2.375 \text{V, } R_{\text{EXT}} = 3.32 \text{k}\Omega \\ &V_{\text{IN}} = 3.3 \text{V, } R_{\text{EXT}} = 15 \text{k}\Omega \\ &V_{\text{IN}} = 5.0 \text{V, } R_{\text{EXT}} = 24.9 \text{k}\Omega \\ &V_{\text{IN}} = 6.6 \text{V, } R_{\text{EXT}} = 49.9 \text{k}\Omega \end{aligned}$		50 70 100 85		μΑ
Binary Input Logic Low Threshold <sup>6</sup>	$V_{\text{B-Low}}$				0.8	
Binary Input Logic High Threshold <sup>6</sup>	$V_{\text{B-High}}$		1.8			

#### NOTES:

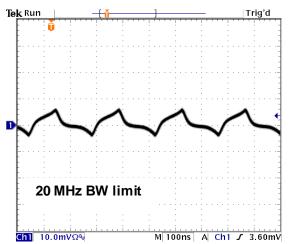
- 1. Parameter guaranteed by design.
- 2. Maximum output current may need to be de-rated, based on operating condition, to meet T<sub>1</sub> requirements.
- 3. POK threshold when  $V_{OUT}$  is rising is nominally 92%. This threshold is 90% when  $V_{OUT}$  is falling. After crossing the 90% level, there is a 256 clock cycle (~50us) delay before POK is de-asserted. The 90%, 92%, 115%, and 120% levels are nominal values. Expect these thresholds to vary by  $\pm 3\%$ .
- 4. On the falling edge of VOUT below 90% of programmed value, POK response is delayed for the duration of the deglitch delay time. Any VOUT glitch shorter than the deglitch time is ignored.
- 5. M/S, MAR1, and MAR2 are ternary. Ternary pins have three logic levels: high, float, and low. These pins are only meant to be strapped to  $V_{IN}$  through an external resistor, strapped to GND, or left floating. Their state cannot be changed while the device is on.
- 6. Binary input pins are EN PB and OCP ADJ.

Rev E

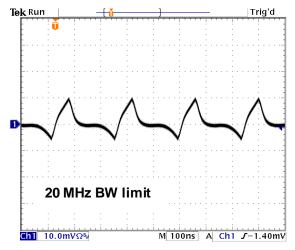
# Typical Performance Characteristics



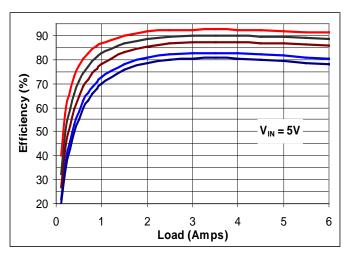
Efficiency  $V_{IN} = 3.3V$  $V_{OUT}$  (From top to bottom) = 2.5, 1.8, 1.2, 1.0V



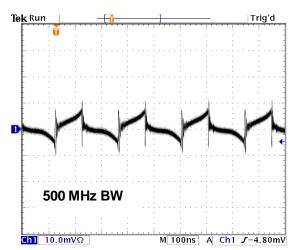
Output Ripple:  $V_{IN} = 3.3V$ ,  $V_{OUT} = 1.2V$ , lout = 6A  $C_{IN} = 2 \times 22 \mu F/1206$ ,  $C_{OUT} = 47 \mu F/1206 + 10 \mu F/0805$ 



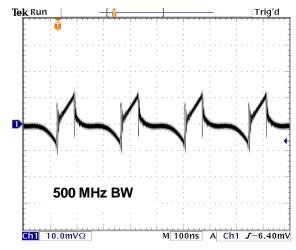
Output Ripple:  $V_{IN} = 5.0V$ ,  $V_{OUT} = 1.2V$ , lout = 6A  $C_{IN} = 2 \times 22 \mu F/1206$ ,  $C_{OUT} = 47 \mu F/1206 + 10 \mu F/0805$ 



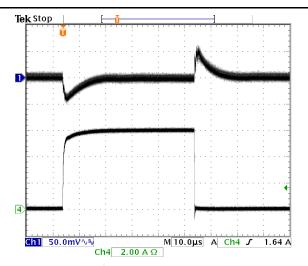
Efficiency  $V_{IN} = 5.0V$  $V_{OUT}$  (From top to bottom) = 3.3, 2.5, 1.8, 1.2, 1.0V



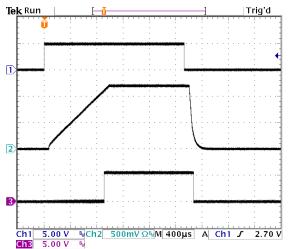
Output Ripple:  $V_{IN} = 3.3V$ ,  $V_{OUT} = 1.2V$ , lout = 6A  $C_{IN} = 2 \times 22 \mu F/1206$ ,  $C_{OUT} = 47 \mu F/1206 + 10 \mu F/0805$ 



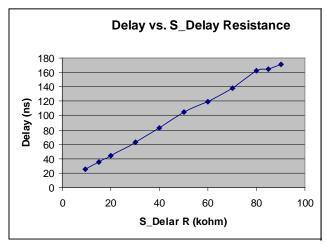
Output Ripple:  $V_{IN} = 5.0V$ ,  $V_{OUT} = 1.2V$ , lout = 6A  $C_{IN} = 2 \times 22 \mu F/1206$ ,  $C_{OUT} = 47 \mu F/1206 + 10 \mu F/0805$ 



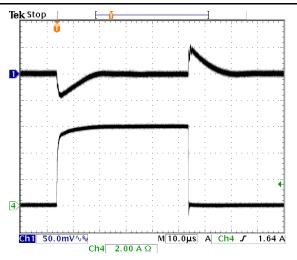
Load Transient:  $V_{IN} = 5.0V$ ,  $V_{OUT} = 1.2V$ Ch.1:  $V_{OUT}$ , Ch.4:  $I_{LOAD}$   $0 \leftrightarrow 6A$  (slew rate  $\geq 10A/\mu S$ )  $C_{\text{IN}} \approx 50 \mu F$ ,  $C_{\text{OUT}} \approx 50 \mu F$  $R_A = 150k\Omega$ ,  $C_A = 27pF$  (see Figure 4)



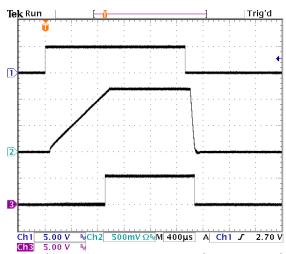
Power Up/Down at No Load:  $V_{IN}/V_{OUT} = 5.0V/1.2V$ , 15nF soft-start capacitor, Ch.1: ENABLE, Ch.2: V<sub>OUT</sub>, Ch.3; POK



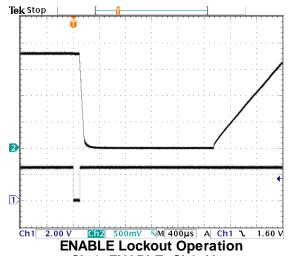
Delay vs. S\_Delay Resistance



Load Transient:  $V_{IN} = 3.3V$ ,  $V_{OUT} = 1.2V$ Ch.1:  $V_{OUT}$ , Ch.4:  $I_{LOAD}$   $0 \leftrightarrow 6A$  (slew rate  $\geq 10A/\mu S$ )  $C_{\text{IN}} \approx 50 \mu F, \; C_{\text{OUT}} \approx 50 \mu F$  $R_A = 100k\Omega$ ,  $C_A = 47pF$  (see Figure 4)



Power Up/Down into  $0.2\Omega$  load:  $V_{IN}/V_{OUT} = 5.0V/1.2V$ , 15nF soft-start capacitor, Ch.1: ENABLE, Ch.2: V<sub>OUT</sub>, Ch.3; POK



Ch.1: ENABLE, Ch2: Vout

## **Block Diagram**

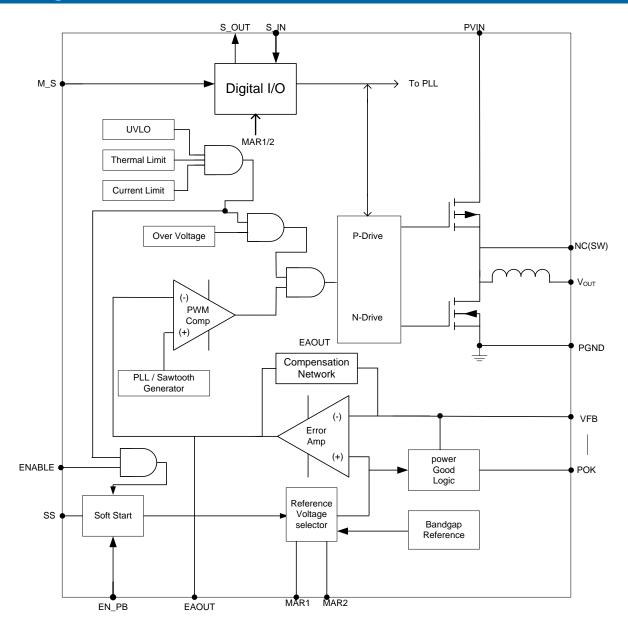


Figure 3. System Block Diagram

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October 11, 2013

# **Functional Description**

# **Synchronous Buck Converter**

The EN5364QI is a synchronous, programmable power supply with integrated power MOSFET switches and integrated inductor. The nominal input voltage range is 2.375-6.6V. The output voltage is programmed using an external resistor divider network. The feedback control loop is a type III, voltage-mode, and the device uses a low-noise PWM topology. Up to 6A of continuous

output current can be drawn from this converter. The 4MHz operating frequency enables the use of small-size input and output capacitors.

The power supply has the following protection features:

- Over-current protection with hiccup mode.
- Short Circuit protection.
- Thermal shutdown with hysteresis.

 Under-voltage lockout circuit to disable the converter output when the input voltage is less than approximately 2.2V

#### **Enable Operation**

The ENABLE pin provides a means to start normal operation or to shut down the device. A logic high will enable the converter into normal operation. When the ENABLE pin is asserted (high) the device will undergo a normal soft start. A logic low will disable the converter. A logic low will power down the device in a controlled manner and the device is subsequently shut down. The device will remain shut-down for the duration of the ENABLE lockout time (see Electrical Characteristics Table). If the ENABLE signal is re-asserted during this time, the device will power up with a normal soft-start at the end of the ENABLE lockout time.

The Enable threshold is a precision Analog voltage rather than a digital logic threshold. Precision threshold along with choice of soft-start capacitor helps to accurately sequence multiple power supplies in a system.

#### **Frequency Synchronization**

The switching frequency of the DC/DC converter can be phase-locked to an external clock source to move unwanted beat frequencies out of band. To avail this feature, the ternary input MS pin should be floating or pulled low. The internal switching clock of the DC/DC converter can then be phase locked to a clock signal applied to S IN pin. An activity detector recognizes the presence of an external clock signal and automatically phase-locks the internal oscillator to this external clock. Phase-lock will occur as long as the input clock frequency is within ±10% of the free running frequency (see Electrical Characteristics table). When no clock signal is present, the device reverts to the free running frequency of the internal oscillator. The external clock input may be swept between 3.6 MHz and 4.4 MHz at repetition rates of up to 10 kHz in order to reduce EMI frequency components.

# Master / Slave Parallel Operation

Multiple EN5364QI devices may be connected in parallel in a Master/Slave configuration to handle

load currents greater than device maximum rating. The device is set in Master mode by pulling the ternary M/S pin low or in Slave mode by pulling M/S pin high to  $V_{\rm IN}$  through an external resistor. When this pin is in Float state, parallel operation is not possible. In master mode, the internal PWM signal is output on the S\_OUT pin. This PWM signal from the Master can be fed to one or more Slave devices at its S\_IN input. The Slave device acts like an extension of the power FETs in the Master. As a practical matter, paralleling more than 4 devices may be very difficult from the view point of maintaining very low impedance in  $V_{\rm IN}$  and  $V_{\rm OUT}$  lines.

The table below summarizes the different configurations for the S\_IN and S\_OUT pins depending on the condition of the M/S pin:

When M/S pin is:	High (Slave)	Low (Master)	Float
S_IN input should be:	S_OUT from Master	External Sync needed (NC fo clock)	
S_OUT is equal to (subject to S_DELAY):	Same duty cycle as S_IN	Same duty cycle as internal PWM	S_IN or internal clock

Please contact Altera Power Applications support for more information on Master / Slave operation.

### Phase Delay

In all cases, S\_OUT can be delayed with respect to internal switching clock or the clock applied to S\_IN. Multiple EN5364QI devices on a system board may be daisy chained to reduce or eliminate input ripple as well as avoiding beat frequency components. The EN5364QIs can all be phase locked by feeding S\_OUT of one device into S\_IN of the next device in a daisy chain. All the switchers now run at a common frequency. The delay is controlled by the value of a resistor connected between S\_DELAY and AGND pins. The magnitude of this delay as a function of S\_DELAY resistor is shown in the Electrical Characteristics table. See Figures 6 and 7 for an example of using phase delay.

## Margining

Using MAR1 and MAR2 pins, the nominal output

voltage can be increased / decreased by 2.5, 5 or 10% for system compliance, reliability or other tests. The POK threshold voltages scale with the margined output voltages. The following table provides the possible combinations:

MAR1	MAR2	Output Modulation
Float	Float	0%
Low	Low	-2.5%
High	Low	+2.5%
Low	High	-5%
High	High	+5%
Low	Float	-10%
High	Float	+10%
Float	High	0%, Delay Bypass
Float	Low	Reserved

Note: Low means tie to GND. High means tie to  $\overline{V}_{IN}$  as shown in Figure 5.

As shown above, when MAR1 is floating, and MAR2 is high, the device enters the delay bypass mode. In this mode, the delay from the internal clock or S\_IN to S\_OUT is almost eliminated (see Electrical Characteristics table).

#### **Soft-Start Operation**

The SS pin in conjunction with a small external capacitor between this pin and AGND provides the soft start function to limit the in-rush current during start-up. During start-up of the converter the reference voltage to the error amplifier is gradually increased to its final level as an internal current source of typically 10uA charges the soft start capacitor. The typical soft-start time for the output to reach regulation voltage, from when AVIN >  $V_{UVLO}$  and ENABLE crosses its logic high threshold, is given by:

$$T_{SS} = (C_{SS} * 65K\Omega) \pm 25\%$$

Where the soft-start time  $T_{SS}$  is in seconds and the soft-start capacitance  $C_{SS}$  is in Farads. Typically, around 15nF is recommended. The soft-start capacitor should be between 4.7nF and 100nF. A proper choice of SS capacitance can be used advantageously for power supply sequencing using the precision Enable threshold.

During a soft-start cycle, when the soft-start capacitor voltage reaches 0.60V, the output has

reached its programmed regulation range. Note that the soft-start current source will continue to charge the SS capacitor beyond 0.6V. During normal operation, the soft-start capacitor will charge to a final value of ~1.5V.

#### **Soft-Shutdown Operation**

When the Enable signal is de-asserted, the softstart capacitor is discharged in a controlled manner. Thus the output voltage ramps down gradually. The internal circuits are kept active for the duration of soft-shutdown, thereafter they are deactivated.

#### **Pre-Bias Operation**

When EN\_PB is asserted, the device will support a monotonic output voltage ramp if the output capacitor is charged to a pre-bias level. Proprietary circuit ensures the output voltage ramps monotonically from pre-bias voltage to the programmed output voltage. Monotonic start-up is guaranteed by design for pre-bias voltages between 20% and 85% of the programmed output voltage. This feature is not supported when ENABLE is tied to  $V_{\rm IN}$ .

### **POK Operation**

The POK signal indicates if the output voltage is within a specified range. The POK signal is asserted when the rising output voltage crosses 92% (nominal) of the programmed output voltage. POK is de-asserted ~50us (256 clock cycles) after the falling output voltage crosses 90% (nominal) of the programmed voltage. POK is also de-asserted if the output voltage exceeds 120% of the programmed output. If the feedback loop is broken, POK will remain de-asserted (output < 92% of programmed value), and the output voltage will equal the input voltage. If however, there is a short across the PFET, and the feedback is in place, POK will be de-asserted as an over voltage condition. The power NFET is also turned on, resulting in a large input supply current. This in turn is expected to trip the OCP of the EN5364QI input power supply.

POK is an open drain output. It requires an external pull up. Multiple EN5364QI's POK pins may be connected to a single pull up. The open drain NFET is designed to sink up to 4mA. The

pull-up resistor value should be chosen accordingly for when POK is logic low.

#### Input Under-Voltage Lock-Out (UVLO)

When the input voltage is below a required voltage level  $(V_{UVLO})$  for normal operation, the converter switching is inhibited. The lock-out threshold has hysteresis to prevent chatter. UVLO is implemented to ensure that operation does not begin before there is adequate voltage to properly bias all internal circuitry.

#### **Over-Current Protection (OCP)**

The current limit and short-circuit protection is achieved by sensing the current flowing through a sense P-FET. When the sensed current exceeds the current limit, both NFET and PFET switches are turned off. If the over-current condition is removed, the over-current protection circuit will re-enable the PWM operation. If the over-current condition persists, the circuit will continue to protect the device.

The OCP trip point is nominally set to 175% of maximum rated load. In the event the OCP circuit trips, the device enters a hiccup mode. The device is disabled for ~10msec and restarted with a normal soft-start. This cycle can continue indefinitely as long as the over current condition persists. During soft-start at power up or fault recovery, the hiccup mode is disabled and the device has cycle-by-cycle current limiting.

#### **Thermal Overload Protection**

Thermal shutdown will disable operation when the Junction temperature exceeds approximately 150°C. Once the junction temperature drops by approximately 20°C, the converter will re-start with a normal soft-start.

#### Compensation

The EN5364 uses of a type III compensation network. Most of this network is integrated. However a phase lead capacitor is required in parallel with upper resistor of the external divider network (see Figure 4). This network results in a wide loop bandwidth and excellent load transient performance. It is optimized for around 50µF of output filter capacitance at the voltage sensing point. Additional decoupling capacitance may be placed beyond the voltage sensing point outside the control loop. Voltage-mode operation provides high noise immunity at light load. Further, voltage-mode control provides superior impedance matching to ICs processed in sub 90nm technologies.

In exceptional cases modifications to the compensation may be required. The EN5364QI provides the capability to modify the control loop response to allow for customization for specific applications. For more information, contact Altera Power Applications support.

# **Application Information**

#### **Output Voltage Programming**

The EN5364 output voltage is determined by the voltage presented at the VFB pin. This voltage is set by way of a resistor divider between  $V_{OUT}$  and AGND with the midpoint going to VFB. A phase lead capacitor  $C_A$  is also required for stabilizing the loop. Figure 4 shows the required components and the equations to calculate their values. Please note the equations below are written to optimize the control loop as a function of input voltage.

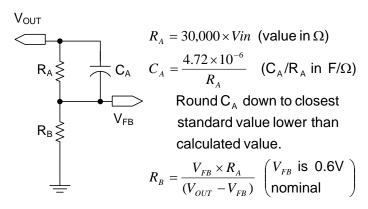


Figure 4: Output voltage resistor divider and phaselead capacitor calculation. The equations need to be followed in the order written above.

#### **Input Capacitor Selection**

The EN5364QI requires between 20-40uF of input capacitance. Low ESR ceramic capacitors are required with X5R or X7R dielectric formulation. Y5V or equivalent dielectric formulations must not be used as these lose capacitance with frequency, temperature and bias voltage.

In some applications, lower value ceramic capacitors may be needed in parallel with the larger capacitors in order to provide high frequency decoupling.

#### **Recommended Input Capacitors**

Description	MFG	P/N
10uF, 10V, 10% X7R, 1206	Murata	GRM31CR71A106KA01L
(2-4 capacitors needed)	Taiyo Yuden	LMK316B7106KL-T
22uF, 10V, 20% X5R, 1206 (1-2 capacitors needed)	Murata	GRM31CR61A226ME19L
	Taiyo Yuden	LMK316BJ226ML-T
47uF, 6.3V, 20% X5R, 1206 (1 capacitor needed)	Murata	GRM31CR60J476ME19L
	Taiyo Yuden	JMK212BJ476ML-T

#### **Output Capacitor Selection**

The EN5364 has been optimized for use with about  $50\mu F$  of output filter capacitance. Up to  $100\mu F$  can be placed at the voltage sensing point. Additional capacitance may be placed beyond the voltage sensing point outside the control loop. For the output filter, low ESR X5R or X7R ceramic capacitors are required. Y5V or equivalent dielectric formulations must not be used as these lose capacitance with frequency, temperature and bias voltage.

## **Recommended Output Capacitors**

Description	MFG	P/N
47uF, 6.3V, 20% X5R, 1206	Murata	GRM31CR60J476ME19L
(1 capacitorneeded)	Taiyo Yuden	JMK212BJ476ML-T
10uF, 6.3V, 10% X5R, 0805	Murata	GRM21BR60J106KE19L
(Optional 1 capacitor in parallel with 47uF above)	Taiyo Yuden	JMK212BJ106KG-T

Output ripple voltage is primarily determined by the aggregate output capacitor impedance. At the 4MHz switching frequency, the capacitor impedance, denoted as Z, is comprised mainly of effective series resistance, ESR, and effective series inductance, ESL: Z = ESR + ESL.

Placing multiple capacitors in parallel reduces the impedance and hence will result in lower ripple voltage.

$$\frac{1}{Z_{Total}} = \frac{1}{Z_1} + \frac{1}{Z_2} + \dots + \frac{1}{Z_n}$$

Typical ripple versus capacitor arrangement is given below:

	put Capacitor onfiguration	Typical Output Ripple (mVp-p) (as measured on EN5364QI Evaluation Board) <sup>†</sup>
	1x47uF	30mV
1x4	7uF + 1x10uF	15mV

<sup>†</sup> 20 MHz bandwidth limit

#### **Ternary Pin Inputs**

The three ternary pins MAR1, MAR2, and M/S have three possible states. In the Low state, the pins are to be tied to GND. In the floating state, nothing is to be connected to the pins. In the High state, they are to be tied to  $V_{\text{IN}}$  through an external resistor  $R_{\text{EXT}}$  in order to limit the input current to the pin (see Figure 5). The Electrical Characteristics table lists, as a function of  $V_{\text{IN}}$ , some recommended values for  $R_{\text{EXT}}$ , and the resulting input currents.

## Frequency Sync & Phase Delay

The EN5364 can be synchronized to an external clock source or to another EN5364 in order to eliminate unwanted beat frequencies. more synchronized Furthermore, two or EN5364's can have a programmable phase delay with respect to each other to minimize input voltage ripple and noise. An example of synchronizing three EN5364's with approximately equal phase delay between them is shown in Figures 6 and 7. The lowest allowable value for the S DELAY resistor is  $10k\Omega$ .

## **Power Up/Down Sequencing**

During power-up, ENABLE should not be asserted before PVIN, and PVIN should not be asserted before AVIN. The PVIN should never be powered when AVIN is off. During power

down, the AVIN should not be powered down before the PVIN. Tying PVIN and AVIN or all three pins (AVIN, PVIN, ENABLE) together during power up or power down meets these requirements.

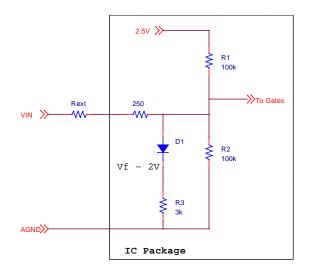


Figure 5: Equivalent circuit of a ternary pin (MAR1, MAR2, or M/S) input buffer. To get a logic High on a ternary input, pull the pin to  $V_{\rm IN}$  through an external resistor  $R_{\rm EXT}$ . See Electrical Characteristics table for some recommended  $R_{\rm EXT}$  values as a function of  $V_{\rm IN}$  and the resulting input currents.

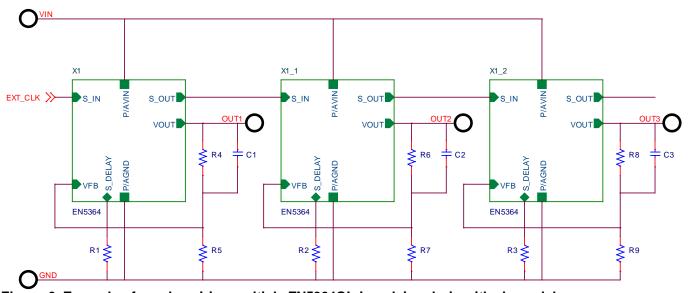


Figure 6: Example of synchronizing multiple EN5364Qls in a daisy chain with phase delay.

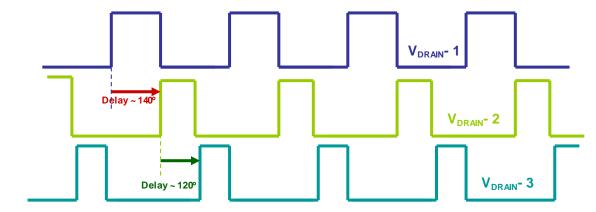
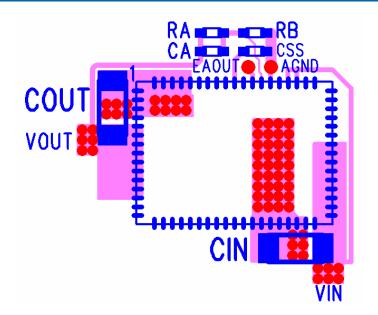


Figure 7: Example of a possible way to synchronize and use delays advantageously to minimize input ripple. R1 ~  $39k\Omega$ , R2 ~  $33k\Omega$ . (Refer to Figure 6 for R1 and R2.) R3 does not matter in this case.

## **Layout Recommendations**



- RA and RB are voltage programming resistors.
- CA is used for loop compensation.
- CSS is the soft-start capacitor.
- AGND via is also a test point.
- Test point added for EAOUT.

Figure 8: Critical Components and Layer 1 Copper for Minimum Footprint

Figure 8 above shows critical components and layer 1 traces of the recommended EN5364 layout for minimum footprint with ENABLE tied to  $V_{\text{IN}}$ . Alternate ENABLE configurations, and other small signal pins need to be connected and routed according to specific customer application. Please see the Gerber files at <a href="https://www.altera.com/enpirion">www.altera.com/enpirion</a> for exact dimensions and other layers.

Recommendation 1: Input and output filter capacitors should be placed on the same side of the PCB, and as close to the EN5364QI package as possible. They should be connected to the device with very short and wide traces. Do not use thermal reliefs or spokes when connecting the capacitor pads to the respective nodes. The +V and GND traces between the capacitors and the EN5364QI should be as close to each other as possible so that the gap between the two nodes is minimized, even under the capacitors.

**Recommendation 2:** The system ground plane referred to in recommendations 2 and 3 should be the first layer immediately below the surface layer. This ground plane should be continuous and un-interrupted below the converter and the input/output capacitors.

Recommendation 3: The large and small

thermal pads underneath the component must be connected to the system ground plane through as many vias as possible. The drill diameter of the vias should be 0.33mm, and the vias must have at least 1 oz. copper plating on the inside wall, making the finished hole size around 0.20-0.26mm. Do not use thermal reliefs or spokes to connect the vias to the ground plane. This connection provides the path for heat dissipation from the converter. Please see figures: 8, 9, and 10.

Recommendation 4: Multiple small vias (the same size as the thermal vias discussed in recommendation 3) should be used to connect ground terminal of the input capacitor and output capacitors to the system ground plane. It is preferred to put these vias along the edge of the GND copper closest to the +V copper. These vias connect the input/output filter capacitors to the GND plane, and help reduce parasitic inductances in the input and output current loops.

**Recommendation 5**: AVIN is the power supply for the small-signal control circuits. It should be connected to the input voltage at a quiet point. In Figure 8 this connection is made at the input capacitor.

Recommendation 6: The layer 1 metal under

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the device must not be more than shown in Figure 8. See the section regarding exposed metal on bottom of package. As with any switch-mode DC/DC converter, try not to run sensitive signal or control lines underneath the converter package on other layers.

**Recommendation 7:** The V<sub>OUT</sub> sense point should be just after the last output filter

capacitor. Keep the sense trace short in order to avoid noise coupling into the node.

**Recommendation 8**: Keep R<sub>A</sub>, C<sub>A</sub>, and R<sub>B</sub> close to the VFB pin (see Figures 4 and 8). The VFB pin is a high-impedance, sensitive node. Keep the trace to this pin as short as possible. Whenever possible, connect R<sub>B</sub> directly to the AGND pin instead of going through the GND plane.

#### **Thermal Considerations**

The Altera Enpirion EN5364QI DC-DC converter is packaged in an 11 x 8 x 1.85mm 68-pin QFN package. The QFN package is constructed with copper lead frames that have exposed thermal pads. The recommended maximum junction temperature for continuous operation is 125°C. Continuous operation above 125°C will reduce long-term reliability. The device has a thermal overload protection circuit designed to shut it off at an approximate junction temperature value of 150°C.

The silicon is mounted on a copper thermal pad that is exposed at the bottom of the package. There is an additional thermal pad in the corner of the package which provides another path for heat flow out from the package. The thermal resistance from the silicon to the exposed thermal pads is very low. In order to take advantage of this low resistance, the exposed thermal pads on the package should be soldered directly on to a copper ground pad on layer 1 of the PCB. The PCB then acts as a heat sink. In order for the PCB to be an effective heat sink, the device thermal pads should be coupled to copper ground planes using multiple vias (refer to Layout Recommendations section).

The junction temperature,  $T_J$ , is calculated from the ambient temperature,  $T_A$ , the device power dissipation,  $P_D$ , and the device junction-to-ambient thermal resistance,  $\theta_{JA}$  in °C/W:

$$T_{J} = T_{A} + (P_{D})(\theta_{JA})$$

The junction temperature, T<sub>J</sub>, can also be expressed in terms of the device case

temperature,  $T_C$ , and the device junction-to-case thermal resistance,  $\theta_{JC}$  in °C/W, as follows:

$$T_J = T_C + (P_D)(\theta_{JC})$$

The device case temperature,  $T_C$ , is the temperature at the center of the larger exposed thermal pad at the bottom of the package.

The device junction-to-ambient and junction-to-case thermal resistances,  $\theta_{JA}$  and  $\theta_{JC}$ , are shown in the Thermal Characteristics table. The  $\theta_{JC}$  is a function of the device and the 68-pin QFN package design. The  $\theta_{JA}$  is a function of  $\theta_{JC}$  and the user's system design parameters that include the thermal effectiveness of the customer PCB and airflow.

The  $\theta_{JA}$  value shown in the Thermal Characteristics table is for free convection with the device heat sunk (through the thermal pads) to a copper plated four-layer PC board with a full ground and a full power plane following JEDEC EIJ/JESD 51 Standards. The  $\theta_{JA}$  can be reduced with the use of forced air convection. Because of the strong dependence on the thermal effectiveness of the PCB and the system design, the actual  $\theta_{JA}$  value will be a function of the specific application.

When operating on a board with the  $\theta_{JA}$  of the thermal characteristics table, no thermal deratings are needed to operate all the way up to maximum output current.

# Design Considerations for Lead-Frame Based Modules

#### **Exposed Metal on Bottom of Package**

Lead-frames offer many advantages in thermal performance, in reduced electrical lead resistance, and in overall foot print. However, they do require some special considerations.

In the assembly process lead frame construction requires that, for mechanical support, some of the lead-frame cantilevers be exposed at the point where wire-bond or internal passives are attached. This results in several small pads being exposed on the bottom of the package, as shown in Figure 9.

Only the two thermal pads and the perimeter pads are to be mechanically or electrically connected to the PC board. The PCB top layer under the EN5364QI should be clear of any metal (copper pours, traces, or vias) except for the two thermal pads. The "grayed-out" area in Figure 9 represents the area that should be clear of any metal on the top layer of the PCB. Any layer 1 metal under the grayed-out area runs the risk of undesirable shorted connections even if it is covered by soldermask. One exposed pad in the grayed-out area can have  $V_{\rm IN}$  metal under it as noted in Figure 9.

Figure 10 demonstrates the recommended PCB footprint for the EN5364QI. Figure 11 shows the package dimensions.

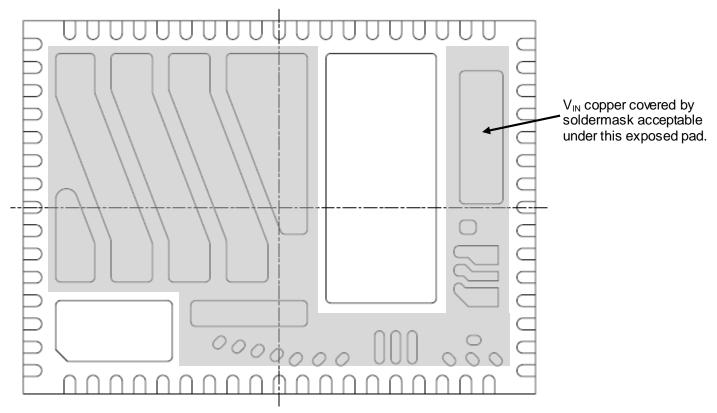


Figure 9: Lead-Frame exposed metal. Grey area highlights exposed metal that is not to be mechanically or electrically connected to the PCB.

17

# PCB Footprint and Package Dimensions

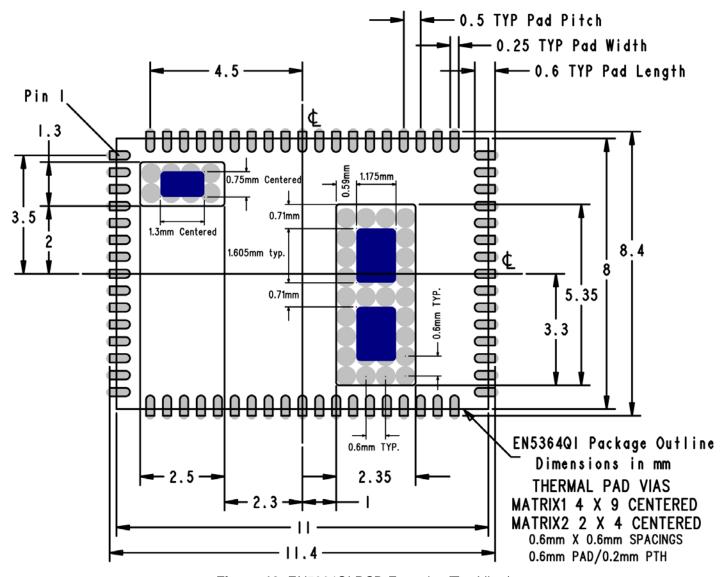


Figure 10: EN5364QI PCB Footprint (Top View)

The solder stencil aperture for the thermal pad is shown in blue and is based on Enpirion power product manufacturing specifications.

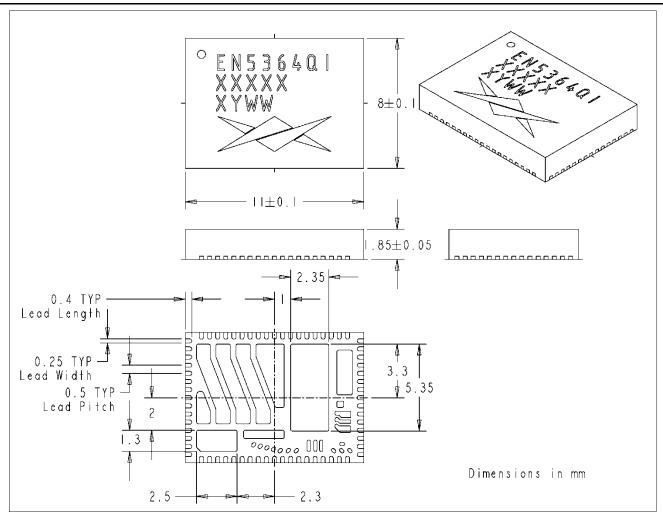


Figure 11. Package Dimensions

## **Contact Information**

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